## NSN 5961-01-110-6856

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-110-6856 **Inclosure Material:** Glass **Overall Length:** 0.265 inches **Terminal Length:** 1.000 inches **Overall Diameter:** 0.096 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: Do-7 **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 90.0 reverse voltage, peak **Current Rating Per Characteristic:** 75.00 milliamperes source cutoff current horsepower metric **Power Rating Per Characteristic:** 250.0 milliwatts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 71.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0